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Ultralow mode-volume photonic crystal nanobeam cavities for high-efficiency coupling to individual carbon nanotube emitters

R. Miura¹, S. Imamura¹, R. Ohta², A. Ishii¹, X. Liu¹, T. Shimada¹, S. Iwamoto², Y. Arakawa² & Y.K. Kato¹

The unique emission properties of single-walled carbon nanotubes are attractive for achieving increased functionality in integrated photonics. In addition to being room-temperature telecom-band emitters that can be directly grown on silicon, they are ideal for coupling to nanoscale photonic structures. Here we report on high-efficiency coupling of individual air-suspended carbon nanotubes to silicon photonic crystal nanobeam cavities. Photoluminescence images of dielectric- and air-mode cavities reflect their distinctly different mode profiles and show that fields in the air are important for coupling. We find that the air-mode cavities couple more efficiently, and estimated spontaneous emission coupling factors reach a value as high as 0.85. Our results demonstrate advantages of ultralow mode-volumes in air-mode cavities for coupling to low-dimensional nanoscale emitters.

¹Institute of Engineering Innovation, The University of Tokyo, Tokyo 113-8656, Japan. ²Institute of Industrial Science, The University of Tokyo, Tokyo 153-8505, Japan. Correspondence and requests for materials should be addressed to Y.K.K. (email: ykato@sogo.t.u-tokyo.ac.jp).

Single-walled carbon nanotubes (CNTs) are known to exhibit unique optical phenomena such as multiple electron-hole pair generation¹ and dimensionality effects on excitons², while their emission properties allow access to spin³ and quantum⁴ degrees of freedom. To utilise such exceptional characteristics in monolithic optical circuits, efficient coupling to photonic structures is essential. In this regard, planar cavities^{5–8} are not ideal as the coupling would be distributed over a continuum of modes.

Nanocavities with small mode-volumes would provide better coupling, and in particular, photonic crystal nanobeam cavities offer flexible control over the cavity fields. In a nanobeam cavity, a periodic array of air holes is etched into a waveguide to form a photonic bandgap, which acts as a Bragg reflector. The bands below the gap are called dielectric bands because the field amplitudes are maximised within the dielectric material, while the bands above the gap are known as air bands since they have large fields in the air holes. The dielectric band modes can be confined by locally reducing the lattice constant a , as the energy of the modes will become higher and the photons will be surrounded by the photonic band gap^{9,10}. Similarly, air-band modes can be confined by introducing a larger lattice constant region^{11,12}.

Here we demonstrate spontaneous emission coupling efficiency exceeding 85% for a single CNT coupled to a silicon photonic crystal nanobeam cavity with an ultralow mode-volume. We take advantage of the excellent optical properties of as-grown air-suspended CNTs^{13–16}, and integrate them with specially designed cavities with large fields in the air, distinctly different from the standard dielectric-mode cavities^{10,17–20}. Our approach is also applicable to other low-dimensional materials, opening up a pathway for efficient use of nanoscale emitters in integrated photonics for both classical and quantum applications.

Results

Coupling individual nanotubes to nanobeam cavities. In Fig. 1a,b, electron microscope images of typical devices are shown. We have performed finite-difference time-domain (FDTD) calculations for these cavity structures to map out the profiles of the fundamental modes. Since nanotubes will be laying at the top surface of the nanobeam, we plot the mode profiles at that height in Fig. 1c,d. As expected, the dielectric-mode cavity has high field amplitudes within the Si material, with evanescent fields extending out the edges. For the air-mode cavity, the fields are mostly distributed within the air holes, with some evanescent fields as in the case of the dielectric-mode cavity. The intense

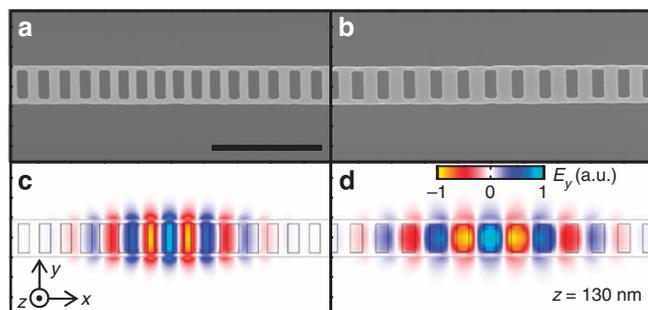


Figure 1 | Photonic crystal nanobeam cavities. (a,b) Scanning electron micrographs of dielectric- and air-mode cavities, respectively. (c,d) Profiles of normalised y -component of electric fields E_y at $z = 130$ nm. The origin of the coordinate system is the centre of the cavity. For **c**, a dielectric-mode cavity with $a = 390$ nm, cavity-centre period of $0.84a$, and 200 nm by 530 nm holes is used for the calculation. For **d**, an air-mode cavity with $a = 430$ nm, cavity-centre period of $1.16a$, and 220 nm by 510 nm holes is used. All panels share the $2\text{-}\mu\text{m}$ scale bar as in **a**.

fields in the air holes should be an advantage compared with cavities that confine most of the optical fields in the high-index medium^{21–23}, because nanotube photoluminescence (PL) is quenched when they are in contact with the substrate^{14,24}. We note that both the cavity modes are transverse electric modes, and therefore the polarisation matches with the emission of nanotubes that are perpendicular to the nanobeams.

To couple individual CNTs to nanobeam cavities, we have fabricated devices shown as a schematic in Fig. 2a. Catalyst particles are placed across a trench from the cavity, and we perform chemical vapour deposition to grow CNTs onto the cavities²². An electron micrograph of a device after nanotube growth is shown in Fig. 2b.

In Fig. 2c, we present a PL spectrum from one such devices taken with an excitation power $P = 1\ \mu\text{W}$ and an excitation wavelength $\lambda_{\text{ex}} = 797$ nm. On top of the broad direct emission from the nanotube, there is a very sharp peak, which is the cavity mode, indicating that the nanotube emission is optically coupled to the cavity. To further characterise the device, PL excitation spectroscopy is performed (Fig. 2d). We observe a single peak in the PL excitation map, demonstrating that this is an isolated single nanotube. Using tabulated data²⁵, the chirality is determined to be (9,8). The intensity of the sharp cavity mode is maximised at the same wavelength as the E_{22} resonance of this tube, showing that the absorption originates from the nanotube and that the cavity mode is excited by the nanotube emission.

Comparison of dielectric- and air-mode cavities. On those devices coupled with single CNTs, we have performed confocal PL imaging to locate the nanotube positions. Figure 3a,b show images from typical dielectric- and air-mode devices, respectively. By determining the positions of the highest PL intensity from images of > 30 devices, the spatial displacements of the nanotubes with respect to the centre of the cavities have been mapped out (Fig. 3c,d). It is possible to identify qualitative differences in the spatial distribution of nanotubes between the two types of cavities. For the dielectric-mode cavities, the emission spot of nanotubes is mostly located at the edges of the nanobeam or

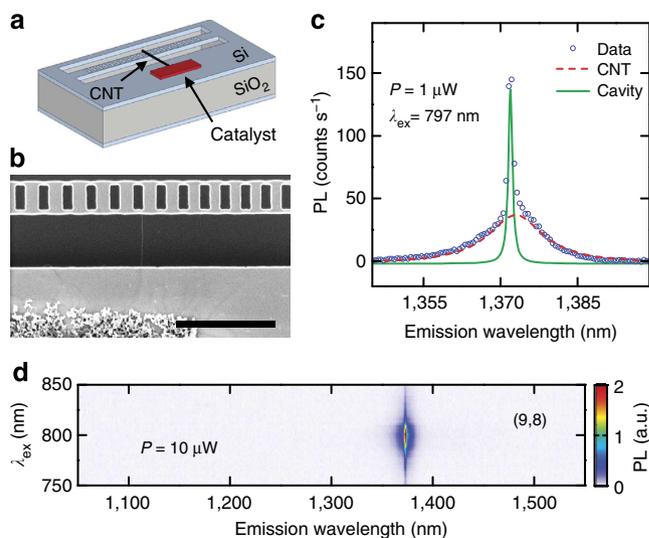


Figure 2 | An individual carbon nanotube coupled to a nanobeam cavity. (a) A schematic of a device. (b) Scanning electron microscope image of a device with a suspended nanotube. Scale bar is $2\ \mu\text{m}$. (c) Typical PL spectrum of an air-mode device coupled to a nanotube. The dots are data and the lines are Lorentzian fits. (d) PL excitation map of the device shown in **c** taken with $P = 10\ \mu\text{W}$ and the laser polarisation perpendicular to the nanobeam.

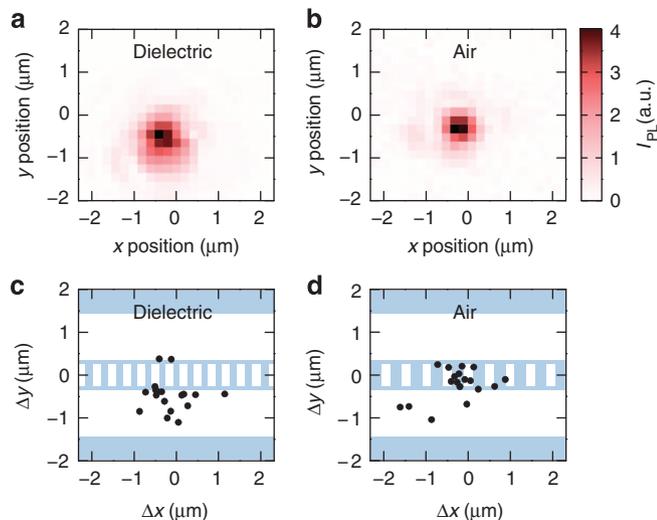


Figure 3 | Spatial distribution of nanotubes that show coupling. (a,b) PL images of representative dielectric- and air-mode cavities, respectively, taken with $\lambda_{\text{ex}} = 800 \text{ nm}$. I_{PL} is obtained by integrating PL over a 0.53 nm wide spectral window centred at the cavity resonance. Excitation powers of $P = 10 \mu\text{W}$ and $20 \mu\text{W}$ are used for (a,b), respectively. The centre of the cavities are taken as the origin of the coordinate system. (c,d) Spatial distribution of PL peak intensity locations for dielectric- and air-mode cavities, respectively. The peak locations are determined by fitting to a two-dimensional Gaussian function, and they are plotted as a function of the displacement from the centre of the cavity.

within the trench, while for the air-mode devices, the emission is on top of the nanobeam itself.

These differences highlight the distinctness of the two types of cavities, and show that coupling occurs predominantly through fields in the air. For dielectric-mode cavities, fields within air holes in the nanobeams are weak, and evanescent fields leaking out from the edges are responsible for coupling (Fig. 1c). In comparison, fields in the air holes dominate for air-mode cavities (Fig. 1d) and nanotubes are coupled when they are placed on top of the air holes.

Next, we further compare the dielectric- and air-mode cavities by analysing the PL spectra. By performing a bi-Lorentzian fit to data (Fig. 2c), we obtain the peak area and the line width for both the nanotube and the cavity emission. We let I_{cav} and I_{CNT} be the PL peak area of the cavity and direct CNT emission, respectively, and use $\beta^* = I_{\text{cav}} / (I_{\text{CNT}} + I_{\text{cav}})$ as a measure of the coupling efficiency. We find that the average value of β^* for the air-mode devices is more than twice the value for the dielectric-mode cavities (Table 1), consistent with the expectation from the mode profiles. We also obtain the quality factor (Q) of the mode from the line width of the cavity peak, but it is likely that the observed values are limited by fabrication errors as the FDTD calculations predict $Q > 10^5$.

High-efficiency coupling. On a few air-mode cavities, we have observed very high values of β^* . In Fig. 4a, we plot the PL spectrum of a device with the highest observed $\beta^* = 0.92$. It is completely dominated by the cavity mode, and the direct nanotube emission is barely observable (Fig. 4b and Supplementary Fig. 1). Since such a spectrum is expected for devices that are lasing, we have performed excitation power dependence measurements in search for any signs of laser oscillation.

In Fig. 4c, excitation power dependence of the PL emission intensities for the cavity and the direct CNT peaks are plotted. The cavity emission increases linearly for powers up to $\sim 20 \mu\text{W}$

Table 1 | β^* and Q of dielectric- and air-mode cavities.

| Cavity type | Number of devices | β^* | Q |
|-------------|-------------------|-----------------|-------------------|
| Dielectric | 16 | 0.18 ± 0.16 | $3,500 \pm 1,400$ |
| Air | 17 | 0.37 ± 0.30 | $2,000 \pm 700$ |

Devices are measured with $P = 10 \mu\text{W}$ and λ_{ex} tuned to the E_{22} resonance. The error values are standard deviations.

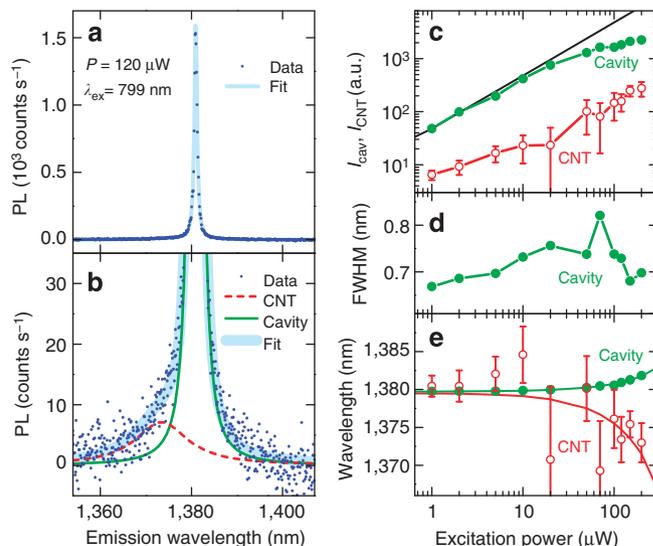


Figure 4 | Efficient coupling of a nanotube to an air-mode cavity.

(a) Photoluminescence (PL) spectrum of an efficiently coupled device taken with $P = 120 \mu\text{W}$ and $\lambda_{\text{ex}} = 799 \text{ nm}$. The dots are data and the line is a fit. (b) An enlarged view of the low-intensity region of the data shown in a. The dots are data, thin solid line is the fit to the cavity mode, thin broken line is the fit to the CNT emission, and the thick line is the bi-Lorentzian fit. (c) Excitation power dependence of I_{cav} (filled circles) and I_{CNT} (open circles). The line is a linear function. (d) P dependence of the cavity mode full-width at half-maximum (FWHM). (e) The centre wavelength of the cavity mode (filled circles) and the nanotube peak (open circles) as a function of P . The solid lines are linear fits. In c–e, $\lambda_{\text{ex}} = 799 \text{ nm}$ is used, and the error bars are smaller than the symbols for the cavity mode.

and becomes slightly sublinear for higher powers, with no indication of a superlinear increase that should occur at a threshold. In addition, under lasing conditions, the direct CNT emission should saturate, because excited state population becomes constant as all the pump power is converted to cavity photon population²⁶. We do not observe such saturation but the CNT peak increases linearly throughout all the powers. Furthermore, the line width of the cavity mode plotted in Fig. 4d does not show the narrowing expected during lasing. From all of these observations, it is unlikely that laser oscillation is taking place.

Under the assumption that stimulated emission is negligible, we can attribute all of the PL to spontaneous emission. Letting γ_{cav} and γ_{CNT} be the spontaneous emission rate into the cavity mode and all the other modes, respectively, the spontaneous emission coupling factor β is given by

$$\beta = \frac{\gamma_{\text{cav}}}{\gamma_{\text{CNT}} + \gamma_{\text{cav}}} = \frac{I_{\text{cav}}}{(\eta_{\text{cav}}/\eta_{\text{CNT}})I_{\text{CNT}} + I_{\text{cav}}}, \quad (1)$$

where η_{cav} and η_{CNT} are collection efficiencies for the cavity mode and direct nanotube emission, respectively (Supplementary Note 1). A conservative estimate of β is made by taking the largest possible value of the ratio $\eta_{\text{cav}}/\eta_{\text{CNT}}$. We let $\eta_{\text{cav}} = 1$,

supposing that all of the light emitted from the cavity mode into the upper hemisphere is collected by the objective. For the direct nanotube emission, we use the dipole radiation pattern as if the nanotube is emitting into free space, although we expect higher collection efficiencies because of reduced emission rate for in-plane directions caused by the photonic bandgap. This results in $\eta_{\text{CNT}} = 0.49$ with the numerical aperture of 0.8 for the objective lens. Using these values and the fitting parameters for the data shown in Fig. 4a,b, we obtain $\beta = 0.85$.

Discussion

It is remarkable that the value of β is already comparable with those for the well-established quantum-dot microcavity systems^{17,18,27–29}, particularly because the Purcell effect is limited by the broad line width of nanotube emitters³⁰. Nevertheless, such a high value of β is reasonable because of ultralow mode-volume of the air-mode cavities. From the FDTD calculation shown in Fig. 1d, mode volume $V = 2.37 \times 10^{-2}(\lambda/n)^3$ is obtained, where $\lambda = 1.38 \mu\text{m}$ is the cavity resonance wavelength, and $n = 1$ is the index of refraction for air. The maximum spontaneous emission enhancement factor is given by $F = (3\lambda^3 Q_e)/(4\pi^2 n^3 V) = 316$, where we use Q of the emitter $Q_e = 99$ instead of the cavity Q , as the nanotube emission line width is much wider than the cavity line width³⁰. Even at the top surface of the nanobeam where the nanotubes are placed, an enhancement factor over 100 is obtained within the centre air-hole, easily explaining the observed high β .

Finally, we would like to comment on the behaviour at higher powers. In Fig. 4e, power dependence of the centre wavelengths for the cavity mode and the nanotube peak are plotted. The cavity redshifts linearly with power due to heating¹⁷, while the nanotube peak blueshifts as observed previously¹⁴. As a result, the cavity mode and the nanotube emission become detuned, and therefore the coupling becomes weaker. At the highest power, the detuning is 8.8 nm, and this is likely the cause of the sublinear increase of cavity mode emission at high powers (Fig. 4c).

Although we did not find any signs of laser oscillations so far, with such an efficient coupling, it is expected that optimisation of cavity design and fabrication would ultimately lead to lasing of individual carbon nanotubes. The air-mode cavities with ultralow mode-volumes should also allow higher coupling efficiencies for other low-dimensional materials with weak dielectric screening^{31,32}.

Methods

Photonic crystal nanobeam fabrication. We fabricate the photonic crystal nanobeam cavities from silicon-on-insulator substrates with 260 nm of top Si layer and 2 μm of buried oxide. Electron beam lithography and dry etching processes are used to form the nanobeam structure with a width of 670 nm, and the buried oxide layer is removed by wet etching. The cavities are designed to have reduced or increased lattice constant in a parabolic manner^{9,10,18} over 12 periods for dielectric-mode and air-mode cavities, respectively. The lattice constants and the hole sizes have been chosen to match the nanotube emission wavelengths.

PL microscopy. The emission properties of devices are characterised using a home-built confocal microspectroscopy system^{14,21}. The objective lens has a numerical aperture of 0.8 and a working distance of 3.4 mm, and a pinhole corresponding to $\sim 3 \mu\text{m}$ diameter at the image plane is used for confocal collection. The samples are excited with a wavelength-tunable continuous-wave Ti:sapphire laser, and PL is detected by an InGaAs photodiode array attached to a spectrometer. The laser polarisation angle is adjusted to maximise the PL signal unless otherwise noted, and all measurements are done in air at room temperature. The samples are mounted on an automated three-dimensional stage, allowing for thousands of devices to be interrogated overnight to identify devices coupled to single nanotube emitters.

References

- Gabor, N. M., Zhong, Z., Bosnick, K., Park, J. & McEuen, P. L. Extremely efficient multiple electron-hole pair generation in carbon nanotube photodiodes. *Science* **325**, 1367–1371 (2009).

- Miyauchi, Y. *et al.* Brightening of excitons in carbon nanotubes on dimensionality modification. *Nat. Photon.* **7**, 715–719 (2013).
- Stich, D. *et al.* Triplet-triplet exciton dynamics in single-walled carbon nanotubes. *Nat. Photon.* **8**, 139–144 (2014).
- Hofmann, M. S. *et al.* Bright, long-lived and coherent excitons in carbon nanotube quantum dots. *Nat. Nanotech.* **8**, 502–505 (2013).
- Xia, F., Steiner, M., Lin, Y.-M. & Avouris, P. A microcavity-controlled, current-driven, on-chip nanotube emitter at infrared wavelengths. *Nat. Nanotech.* **3**, 609–613 (2008).
- Gaufrès, E. *et al.* Optical microcavity with semiconducting single-wall carbon nanotubes. *Opt. Express* **18**, 5740–5745 (2010).
- Legrand, D. *et al.* Monolithic microcavity with carbon nanotubes as active material. *Appl. Phys. Lett.* **102**, 153102 (2013).
- Fujiwara, M., Tsuya, D. & Maki, H. Electrically driven, narrow-linewidth blackbody emission from carbon nanotube microcavity devices. *Appl. Phys. Lett.* **103**, 143122 (2013).
- Notomi, M., Kuramochi, E. & Taniyama, H. Ultrahigh-Q nanocavity with 1D photonic gap. *Opt. Express* **16**, 11095–11102 (2008).
- Eichenfield, M., Camacho, R., Chan, J., Vahala, K. J. & Painter, O. A picogram- and nanometre-scale photonic-crystal optomechanical cavity. *Nature* **459**, 550–555 (2009).
- Zhang, Y. *et al.* High-Q/V air-mode photonic crystal cavities at microwave frequencies. *Opt. Express* **19**, 9371–9377 (2011).
- Quan, Q. & Loncar, M. Deterministic design of wavelength scale, ultra-high Q photonic crystal nanobeam cavities. *Opt. Express* **19**, 18529–18542 (2011).
- Mann, D. *et al.* Electrically driven thermal light emission from individual single-walled carbon nanotubes. *Nat. Nanotech.* **2**, 33–38 (2007).
- Moritsubo, S. *et al.* Exciton diffusion in air-suspended single-walled carbon nanotubes. *Phys. Rev. Lett.* **104**, 247402 (2010).
- Sarpkaya, I. *et al.* Prolonged spontaneous emission and dephasing of localized excitons in air-bridged carbon nanotubes. *Nat. Commun.* **4**, 2152 (2013).
- Barkelid, M. & Zwiller, V. Photocurrent generation in semiconducting and metallic carbon nanotubes. *Nat. Photon.* **8**, 47–51 (2014).
- Gong, Y. *et al.* Nanobeam photonic crystal cavity quantum dot laser. *Opt. Express* **18**, 8781–8789 (2010).
- Ohta, R. *et al.* Strong coupling between a photonic crystal nanobeam cavity and a single quantum dot. *Appl. Phys. Lett.* **98**, 173104 (2011).
- Riedrich-Möller, J. *et al.* One- and two-dimensional photonic crystal microcavities in single crystal diamond. *Nat. Nanotech.* **7**, 69–74 (2012).
- Hausmann, B. J. M. *et al.* Coupling of NV centers to photonic crystal nanobeams in diamond. *Nano Lett.* **13**, 5791–5796 (2013).
- Watahiki, R. *et al.* Enhancement of carbon nanotube photoluminescence by photonic crystal nanocavities. *Appl. Phys. Lett.* **101**, 141124 (2012).
- Imamura, S., Watahiki, R., Miura, R., Shimada, T. & Kato, Y. K. Optical control of individual carbon nanotube light emitters by spectral double resonance in silicon microdisk resonators. *Appl. Phys. Lett.* **102**, 161102 (2013).
- Noury, A., Roux, X. L., Vivien, L. & Izard, N. Controlling carbon nanotube photoluminescence using silicon microring resonators. *Nanotechnology* **25**, 215201 (2014).
- Lefebvre, J., Homma, Y. & Finnie, P. Bright band gap photoluminescence from unprocessed single-walled carbon nanotubes. *Phys. Rev. Lett.* **90**, 217401 (2003).
- Ohno, Y. *et al.* Chirality-dependent environmental effects in photoluminescence of single-walled carbon nanotubes. *Phys. Rev. B* **73**, 235427 (2006).
- Yokoyama, H. & Brorson, S. D. Rate equation analysis of microcavity lasers. *J. Appl. Phys.* **66**, 4801–4805 (1989).
- Solomon, G. S., Pelton, M. & Yamamoto, Y. Single-mode spontaneous emission from a single quantum dot in a three-dimensional microcavity. *Phys. Rev. Lett.* **86**, 3903–3906 (2001).
- Strauf, S. *et al.* Self-tuned quantum dot gain in photonic crystal lasers. *Phys. Rev. Lett.* **96**, 127404 (2006).
- Nomura, M., Iwamoto, S., Kumagai, N. & Arakawa, Y. Temporal coherence of a photonic crystal nanocavity laser with high spontaneous emission coupling factor. *Phys. Rev. B* **75**, 195313 (2007).
- van Exter, M. P., Nienhuis, G. & Woerdman, J. P. Two simple expressions for the spontaneous emission factor β . *Phys. Rev. A* **54**, 3553–3558 (1996).
- Gan, X. *et al.* Strong enhancement of light-matter interaction in graphene coupled to a photonic crystal nanocavity. *Nano Lett.* **12**, 5626–5631 (2012).
- Wu, S. *et al.* Control of two-dimensional excitonic light emission via photonic crystal. *2D Mater.* **1**, 011001 (2014).

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The devices were fabricated at the Center for Nano Lithography & Analysis at The University of Tokyo.

Author contributions

Y.K.K. conceived the experiments and supervised the project. R.M. fabricated the devices and performed the measurements. S.Im., R.O. and T.S. helped develop and optimise the device fabrication processes. R.O., S.Iw. and Y.A. contributed to the nanobeam cavity designs and the calculations. S.Im., A.I. and X.L. assisted the microscopy measurements. T.S. captured the electron micrographs. R.M. and Y.K.K. analysed the data and prepared the manuscript. All authors discussed the results and commented on the manuscript.

Additional information

Supplementary Information accompanies this paper at <http://www.nature.com/naturecommunications>

Competing financial interests: The authors declare no competing financial interests.

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